

Low voltage fast-switching NPN power transistor

Features

- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed

Applications

- Voltage regulators
- High efficiency low voltage switching applications

Description

The device is a low voltage NPN transistor with exceptional high gain performance coupled with very low saturation voltage. It is designed in planar technology with "base island" layout.

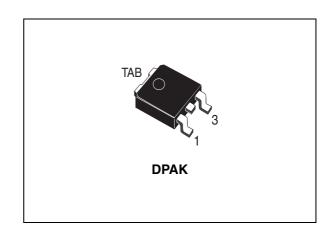


Figure 1. Internal schematic diagram

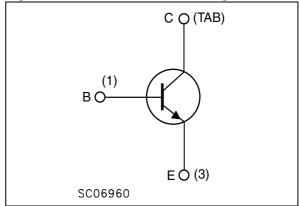


Table 1. Device summary

Order code	Marking	Packages	Packaging
2STD1665T4	D1665	DPAK	Tape and reel

Electrical ratings 2STD1665

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	150	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	65	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	7	V
I _C	Collector current	6	Α
I _{CM}	Collector peak current (t _P < 5ms)	20	Α
I _B	Base current	1	Α
P _{tot}	Total dissipation at T _a = 25 °C	15	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-a} ⁽¹⁾	Thermal resistance junction-ambient max	8.33	°C/W

^{1.} Device mounted on a PCB area of 1 cm²

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified}).$

Table 4. Electrical characteristics

Symbol	Parameter	Test o	conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 120 V V _{CB} = 120 V	T _C = 100 °C			50 1	nΑ μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 7 V				10	nA
V _{(BR)CBO} (1)	Collector-base breakdown voltage (I _E = 0)	I _C = 100 μA		150			٧
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA		65			٧
V _{(BR)EBO} (1)	Emitter-base breakdown voltage (I _C = 0)	I _E = 100 μA		7			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 100 \text{ mA}$ $I_C = 1 \text{ A}$ $I_C = 2 \text{ A}$ $I_C = 6 \text{ A}$ $I_C = 6 \text{ A}$	$I_B = 5 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 150 \text{ mA}$ $I_B = 300 \text{ mA}$		50 100 260 230	50 120 200 600 380	mV mV mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 4 A	I _B = 200 mA		1	1.15	٧
V _{BE(on)} (1)	Base-emitter on voltage	I _C = 4 A	V _{CE} = 1 V		0.85	1	V
h _{FE}	DC current gain	$I_C = 10 \text{ mA}$ $I_C = 2 \text{ A}$ $I_C = 5 \text{ A}$ $I_C = 10 \text{ A}$	$V_{CE} = 1 V$ $V_{CE} = 1 V$ $V_{CE} = 1 V$ $V_{CE} = 1 V$	150 150 90 30	320 310 175 65	350	
C _{CBO}	Collector-base capacitance (I _E =0)	V _{CB} = 10 V	f = 1 MHz		45		pF
t _{on} t _s	Resistive load Turn-on time Storage time Fall time	$I_C = 3 A$ $I_{B(on)} = -I_{B(off)}$ $V_{BB(off)} = -5 V$	V _{CC} = 10 V = 300 mA		90 800 90		ns ns ns

^{1.} Pulse test: pulse duration $\leq 300~\mu s,$ duty cycle $\leq 2~\%$

Electrical characteristics 2STD1665

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

Figure 3. DC current gain

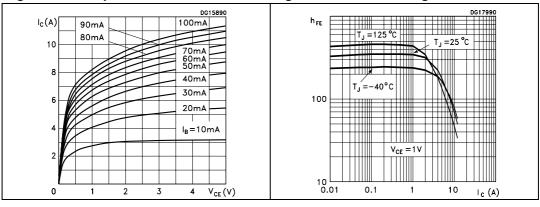


Figure 4. Collector-emitter saturation voltage - $(h_{FE} = 20)$

Figure 5. Collector-emitter saturation voltage - $(h_{FE} = 40)$

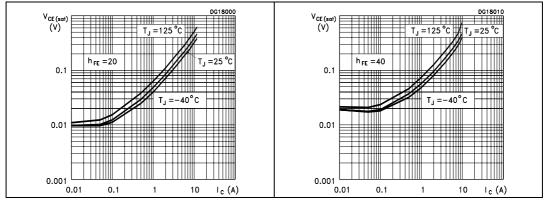
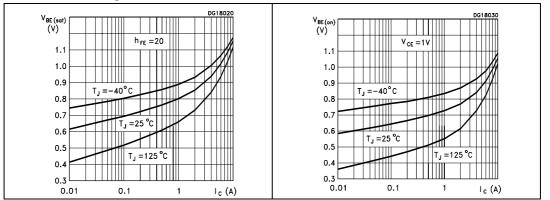


Figure 6. Base-emitter saturation voltage

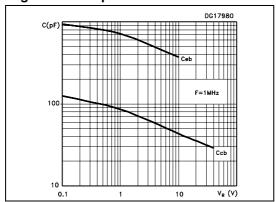
Figure 7. Base-emitter on voltage



t(ns) t (ns) $I_{B(on)} = -I_{B(off)}$ $h_{FE} = 10$ $V_{CC} = 10V$ $V_{CC} = 10V$ $V_{BB(off)} = -5V$ 80 $V_{BB(off)} = -5V$ t, $I_{B(on)} = -I_{B(off)}$ $h_{FE} = 10$ 70 t_s 1000 60 50 40 100 30 td 20 10 L 0.5 1 1.5 2 2.5 Ic (A) 0.5 2 I_C (A)

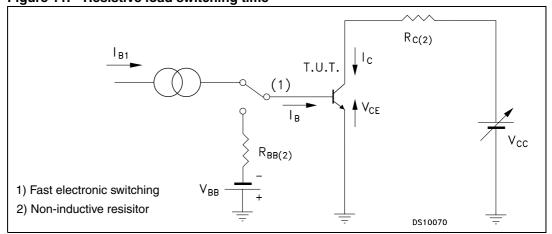
Figure 8. Resistive load switching off Figure 9. Resistive load switching on

Figure 10. Capacitance



2.2 Test circuit

Figure 11. Resistive load switching time



3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

6/10 Doc ID 12350 Rev 3

Table 5. DPAK (TO-252) mechanical data

	AK (10 202) Meditalile	mm	
Dim.	Min.	Тур.	Max.
А	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°

THERMAL PAD

R

GAUGE PLANE

A1

A2

L1

GAUGE PLANE

0068772_G

0068772_G

Figure 12. TO-252 (DPAK) drawings

8/10 Doc ID 12350 Rev 3

2STD1665 Revision history

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
08-May-2006	1	Initial release
27-Mar-2008	2	New graphics
08-Feb-2011	3	Updated Table 2 and 3

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